

Technical Data  
 Data Sheet N0207, Rev. D

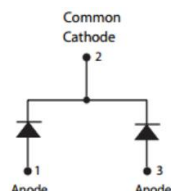

## MBR60100WT SCHOTTKY RECTIFIER



### Features

- 150 °C T<sub>J</sub> operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term Reliability
- Terminals finish: 100% Pure Tin
- This is a Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

### Circuit Diagram



### Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection
- Center tap configuration

### Maximum Ratings:

| Characteristics                                                                        | Symbol                          | Condition                                        | Max.                          | Units |
|----------------------------------------------------------------------------------------|---------------------------------|--------------------------------------------------|-------------------------------|-------|
| Peak Repetitive Reverse Voltage<br>Working Peak Reverse Voltage<br>DC Blocking Voltage | $V_{RRM}$<br>$V_{RWM}$<br>$V_R$ | -                                                | 100                           | V     |
| Average Rectified Forward Current                                                      | $I_{F(AV)}$                     | $T_c=136^{\circ}\text{C}$ , In DC                | 30(Per Leg)<br>60(Per Device) | A     |
| Peak One Cycle Non-Repetitive Surge Current(Per Leg)                                   | $I_{FSM}$                       | 8.3ms, Half Sine pulse, $T_c=25^{\circ}\text{C}$ | 280                           | A     |

### Electrical Characteristics:

| Characteristics                    | Symbol   | Condition                                                                     | Typ.   | Max.   | Units            |
|------------------------------------|----------|-------------------------------------------------------------------------------|--------|--------|------------------|
| Forward Voltage Drop<br>(Per Leg)* | $V_{F1}$ | @ 30A, Pulse, $T_J = 25^{\circ}\text{C}$                                      | 0.81   | 0.90   | V                |
|                                    | $V_{F2}$ | @ 30A, Pulse, $T_J = 125^{\circ}\text{C}$                                     | 0.68   | 0.81   | V                |
| Reverse Current<br>(Per Leg)*      | $I_{R1}$ | @ $V_R$ = rated $V_R$ , $T_J = 25^{\circ}\text{C}$                            | 0.0006 | 1.0    | mA               |
|                                    | $I_{R2}$ | @ $V_R$ = rated $V_R$ , $T_J = 125^{\circ}\text{C}$                           | 0.2    | 20     | mA               |
| Junction Capacitance(Per Leg)      | $C_T$    | @ $V_R = 5\text{V}$ , $T_c = 25^{\circ}\text{C}$ ,<br>$f_{SIG} = 1\text{MHz}$ | 980    | 1200   | pF               |
| Voltage Rate of Change             | $dv/dt$  | -                                                                             | -      | 10,000 | V/ $\mu\text{s}$ |

 \* Pulse width < 300  $\mu\text{s}$ , duty cycle < 2%

## Thermal-Mechanical Specifications:

| Characteristics                             | Symbol          | Condition    | Specification | Units |
|---------------------------------------------|-----------------|--------------|---------------|-------|
| Junction Temperature                        | $T_J$           | -            | -55 to +150   | °C    |
| Storage Temperature                         | $T_{stg}$       | -            | -55 to +150   | °C    |
| Typical Thermal Resistance Junction to Case | $R_{\theta JC}$ | DC operation | 0.5           | °C/W  |
| Approximate Weight                          | wt              | -            | 6.28          | g     |
| Case Style                                  | TO-247AD        |              |               |       |

## Ratings and Characteristics Curves

Figure1 Typical Forward Characteristics

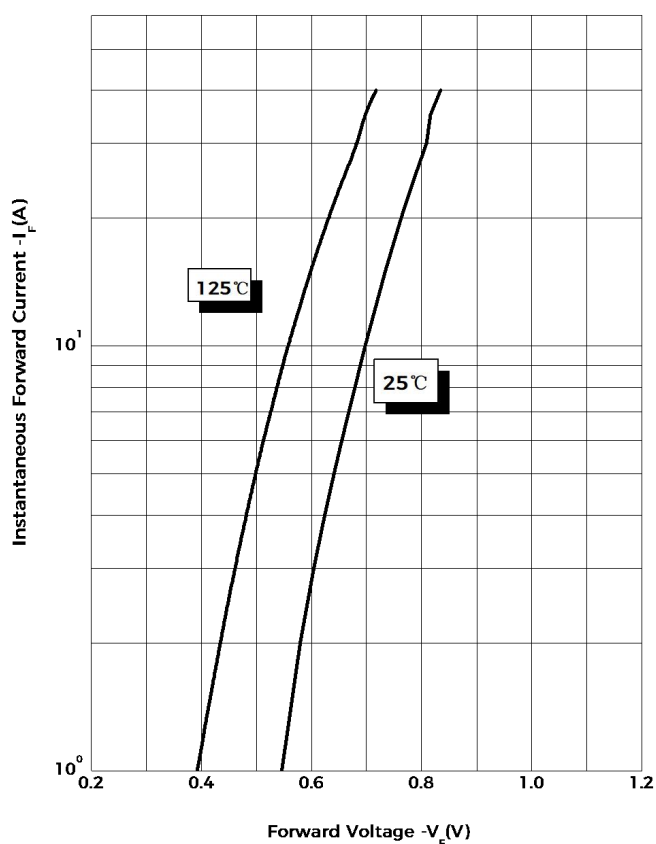


Figure 2 Typical Reverse Characteristics

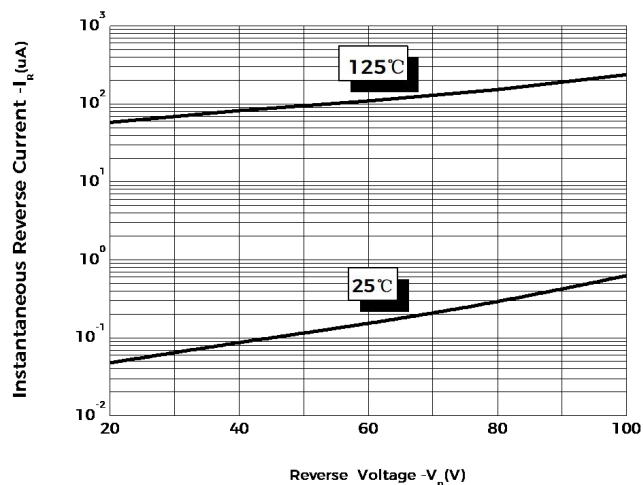
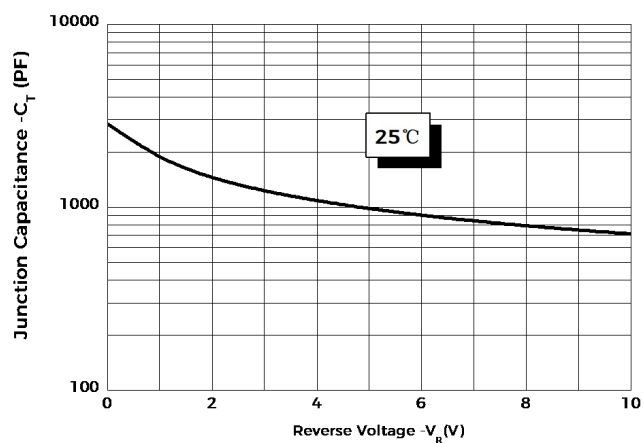
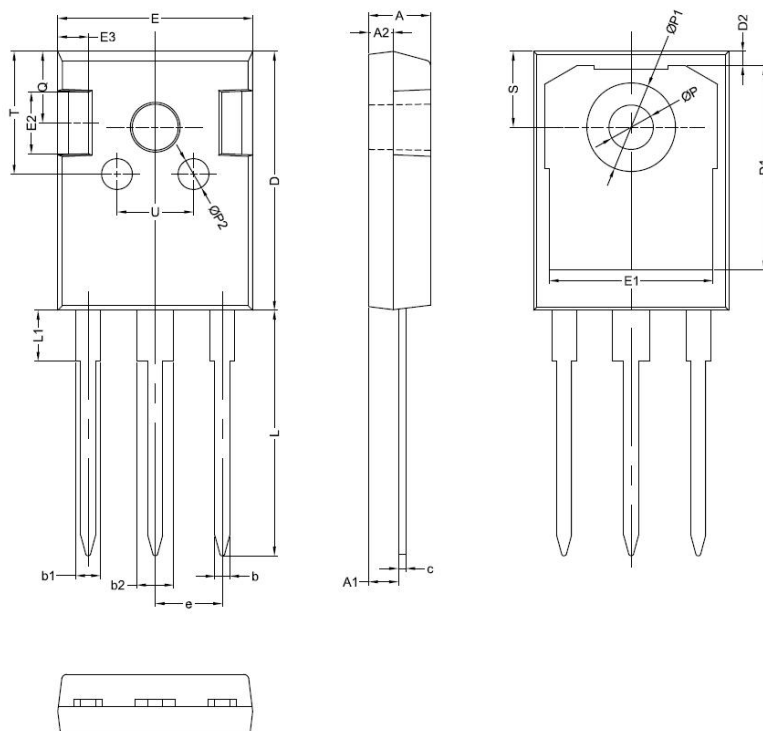


Figure 3 Typical Junction Capacitance



## Mechanical Dimensions TO-247AD

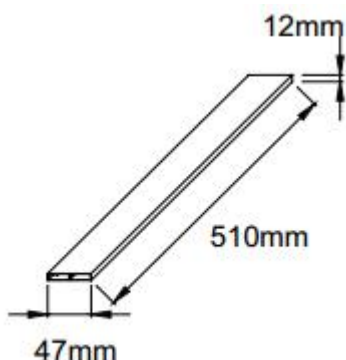


| SYMBOL | Millimeters |       |       |
|--------|-------------|-------|-------|
|        | MIN.        | TYP.  | MAX.  |
| A      | 4.80        | 5.00  | 5.20  |
| A1     | 2.20        | 2.41  | 2.61  |
| A2     | 1.90        | 2.00  | 2.10  |
| b      | 1.10        | 1.20  | 1.40  |
| b1     | 1.80        | 2.00  | 2.20  |
| b2     | 2.80        | 3.00  | 3.20  |
| c      | 0.50        | 0.60  | 0.75  |
| D      | 20.30       | 21.00 | 21.20 |
| D1     |             | 16.55 |       |
| D2     |             | 1.20  |       |
| E      | 15.45       | 15.80 | 16.00 |
| E1     |             | 13.30 |       |
| E2     |             | 5.00  |       |
| E3     |             | 2.50  |       |
| e      |             | 5.44  |       |
| L      | 19.42       | 19.92 | 20.70 |
| L1     |             | 4.13  |       |
| P      | 3.50        | 3.60  | 3.70  |
| P1     | 7.1         |       | 7.40  |
| P2     |             | 2.50  |       |
| Q      |             | 5.80  |       |
| S      | 6.05        | 6.15  | 6.25  |
| T      |             | 10.00 |       |
| U      |             | 6.20  |       |

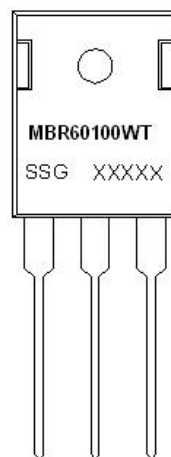
## Ordering Information:

| Device     | Package           | Shipping     |
|------------|-------------------|--------------|
| MBR60100WT | TO-247AD(Pb-Free) | 25pcs / tube |

## Tube Specification



## Marking Diagram



Where XXXXX is YYWWL

MBR = Device Type  
 60 = Forward Current (60A)  
 100 = Reverse Voltage (100V)  
 WT = Configuration  
 SSG = SSG  
 YY = Year  
 WW = Week  
 L = Lot Number

**Cautions:** Molding resin  
 Epoxy resin UL94V-0

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